

CAT5401

Quad Digitally Programmable Potentiometers (DPP™) with 64 Taps and SPI Interface



FEATURES

- Four linear-taper digitally programmable potentiometers
- 64 resistor taps per potentiometer
- End to end resistance 2.5k Ω , 10k Ω , 50k Ω or 100k Ω
- Potentiometer control and memory access via SPI interface: Mode (0, 0) and (1, 1)
- Low wiper resistance, typically 80Ω
- Nonvolatile memory storage for up to four wiper settings for each potentiometer

- Automatic recall of saved wiper settings at power up
- 2.5 to 6.0 volt operation
- Standby current less than 1µA
- 1,000,000 nonvolatile WRITE cycles
- 100 year nonvolatile memory data retention
- 24-lead SOIC, 24-lead TSSOP and BGA
- Industrial temperature range

DESCRIPTION

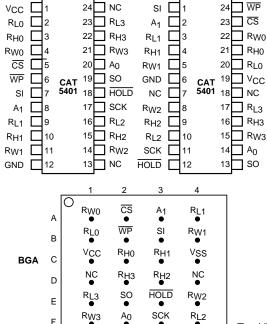
The CAT5401 is four Digitally Programmable Potentiometers (DPPs™) integrated with control logic and 16 bytes of NVRAM memory. Each DPP consists of a series of 63 resistive elements connected between two externally accessible end points. The tap points between each resistive element are connected to the wiper outputs with CMOS switches. A separate 6-bit control register (WCR) independently controls the wiper tap switches for each DPP. Associated with each wiper control register are four 6-bit non-volatile memory data registers (DR) used for storing up to four wiper settings. Writing to the

TSSOP Package (U, Y)

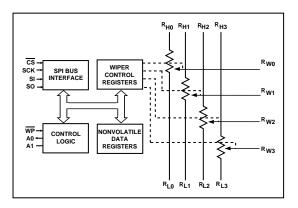
wiper control register or any of the non-volatile data registers is via a SPI serial bus. On power-up, the contents of the first data register (DR0) for each of the four potentiometers is automatically loaded into its respective wiper control register.

The CAT5401 can be used as a potentiometer or as a two terminal, variable resistor. It is intended for circuit level or system level adjustments in a wide variety of applications.

PIN CONFIGURATION SOIC Package (J. W)



FUNCTIONAL DIAGRAM



Top View - Bump Side Down

PIN DESCRIPTION

Pin	Pin	Pin		
(SOIC)	(TSSOP)	(BGA)	Name	Function
1	19	C1	VCC	Supply Voltage
2	20	B1	R _{L0}	Low Reference Terminal for Potentiometer 0
3	21	C2	R _{H0}	High Reference Terminal for Potentiometer 0
4	22	A1	R _{W0}	Wiper Terminal for Potentiometer 0
5	23	A2	<u>cs</u>	Chip Select
6	24	B2	WP	Write Protection
7	1	В3	SI	Serial Input
8	2	А3	A1	Device Address
9	3	A4	R _{L1}	Low Reference Terminal for Potentiometer 1
10	4	C3	R _{H1}	High Reference Terminal for Potentiometer 1
11	5	B4	R _{W1}	Wiper Terminal for Potentiometer 1
12	6	C4	GND	Ground
13	7	D4	NC	No Connect
14	8	E4	R _{W2}	Wiper Terminal for
				Potentiometer 2
15	9	D3	R _{H2}	High Reference Terminal
				for Potentiometer 2
16	10	F4	R _{L2}	Low Reference Terminal
				for Potentiometer 2
17	11	F3	SCK	Bus Serial Clock
18	12	E3	HOLD	Hold
19	13	E2	SO	Serial Data Output
20	14	F2	A0	Device Address, LSB
21	15	F1	R _{W3}	Wiper Terminal for Potentiometer 3
22	16	D2	R _{H3}	High Reference Terminal for Potentiometer 3
23	17	E1	R _{L3}	Low Reference Terminal for Potentiometer 3
24	18	D1	NC	No Connect

PIN DESCRIPTIONS

SI: Serial Input

SI is the serial data input pin. This pin is used to input all opcodes, byte addresses and data to be written to the CAT5401. Input data is latched on the rising edge of the serial clock.

SO: Serial Output

SO is the serial data output pin. This pin is used to transfer data out of the CAT5401. During a read cycle, data is shifted out on the falling edge of the serial clock.

SCK: Serial Clock

SCK is the serial clock pin. This pin is used to synchronize the communication between the microcontroller and the CAT5401. Opcodes, byte addresses or data present on the SI pin are latched on the rising edge of the SCK. Data on the SO pin is updated on the falling edge of the SCK.

A0, A1: Device Address Inputs

These inputs set the device address when addressing multiple devices. A total of four devices can be addressed on a single bus. A match in the slave address must be made with the address input in order to initiate communication with the CAT5401.

RH, RL: Resistor End Points

The four sets of R_H and R_L pins are equivalent to the terminal connections on a mechanical potentiometer.

Rw: Wiper

The four R_W pins are equivalent to the wiper terminal of a mechanical potentiometer.

CS: Chip Select

CS is the Chip select pin. CS low enables the CAT5401 and CS high disables the CAT5401. CS high takes the SO output pin to high impedance and forces the devices into a Standby mode (unless an internal write operation is underway). The CAT5401 draws ZERO current in the Standby mode. A high to low transition on CS is required prior to any sequence being initiated. A low to high transition on CS after a valid write sequence is what initiates an internal write cycle.

WP: Write Protect

 $\overline{\text{WP}}$ is the Write Protect pin. The Write Protect pin will allow normal read/write operations when held high. When $\overline{\text{WP}}$ is tied low, all non-volatile write operations to the Data registers are inhibited (change of wiper control register is allowed). $\overline{\text{WP}}$ going low while CS is still low will interrupt a write to the registers. If the internal write cycle has already been initiated, $\overline{\text{WP}}$ going low will have no effect on any write operation.

HOLD: Hold

The HOLD pin is used to pause transmission to the CAT5401 while in the middle of a serial sequence without having to retransmit entire sequence at a later time. To pause, HOLD must be brought low while SCK is low. The SO pin is in a high impedance state during the time the part is paused, and transitions on the SI pins will be ignored. To resume communication, HOLD is brought high, while SCK is low. (HOLD should be held high any time this function is not being used.) HOLD may be tied high directly to VCC or tied to VCC through a resistor.

SERIAL BUS PROTOCOL

The CAT5041 supports the SPI bus data transmission protocol. The synchronous Serial Peripheral Interface (SPI) helps the CAT5401 to interface directly with many of today's popular microcontrollers. The CAT5041 contains an 8-bit instruction register. The instruction set and the operation codes are detailed in the instruction set table 3.

After the device is selected with \overline{CS} going low the first byte will be received. The part is accessed via the SI pin, with data being clocked in on the rising edge of SCK. The first byte contains one of the six op-codes that define the operation to be performed.

DEVICE OPERATION

The CAT5401 is four resistor arrays integrated with SPI serial interface logic, four 6-bit wiper control registers and sixteen 6-bit, non-volatile memory data registers. Each resistor array contains 63 separate resistive elements connected in series. The physical ends of each array are equivalent to the fixed terminals of a mechanical potentiometer (R_H and R_L). R_H and R_L are symmetrical and may be interchanged. The tap positions between and at the ends of the series resistors are connected to the output wiper terminals (R_W) by a

CMOS transistor switch. Only one tap point for each potentiometer is connected to its wiper terminal at a time and is determined by the value of the wiper control register. Data can be read or written to the wiper control registers or the non-volatile memory data registers via the SPI bus. Additional instructions allows data to be transferred between the wiper control registers and each respective potentiometer's non-volatile data registers. Also, the device can be instructed to operate in an "increment/decrement" mode.

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ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on any Pin with Respect to $V_{SS}^{(1)}$ 2.0V to +V _{CC} +2.0V
V_{CC} with Respect to Ground2.0V to +7.0V
Package Power Dissipation Capability (T _A = 25°C) 1.0W
Lead Soldering Temperature (10 secs) 300°C
Wiper Current <u>±</u> 12mA

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.

Recommended Operating Conditions:									
$V_{CC} = +2.5V \text{ to } +6.0V$									
Temperature	Min	Max							
Industrial -40°C 85°C									

POTENTIOMETER CHARACTERISTICS

Over recommended operating conditions unless otherwise stated.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
RPOT	Potentiometer Resistance (-00)			100		kΩ
R _{POT}	Potentiometer Resistance (-50)			50		kΩ
R _{POT}	Potentiometer Resistance (-10)			10		kΩ
R _{РОТ}	Potentiometer Resistance (-2.5)			2.5		kΩ
	Potentiometer Resistance Tolerance				<u>+</u> 20	%
	R _{POT} Matching				1	%
	Power Rating	25°C, each pot			50	mW
lw	Wiper Current				<u>+</u> 6	mA
Rw	Wiper Resistance	$I_W = \pm 3 \text{mA} @ V_{CC} = 3 \text{V}$			300	Ω
Rw	Wiper Resistance	$I_W = \pm 3 \text{mA} @ V_{CC} = 5 \text{V}$		80	150	Ω
V _{TERM}	Voltage on any R _H or R _L Pin	V _{SS} = 0V	GND		V _C C	V
V _N	Noise	(1)		TBD		nV/√Hz
	Resolution	(1)		1.6		%
	Absolute Linearity (2)	R _{w(n)(actual)} -R _{(n)(expected)} ⁽⁵⁾			<u>+</u> 1	LSB (4)
	Relative Linearity (3)	R _{w(n+1)} -[R _{w(n)+LSB}] ⁽⁵⁾			<u>+</u> 0.2	LSB (4)
TC _{RPOT}	Temperature Coefficient of RPOT	(1)		<u>+</u> 300		ppm/°C
TC _{RATIO}	Ratiometric Temp. Coefficient	(1)			20	ppm/°C
C _H /C _L /C _W	Potentiometer Capacitances	(1)		10/10/25		pF
fc	Frequency Response	$R_{POT} = 50k\Omega$		0.4		MHz

Notes:

- (1) This parameter is tested initially and after a design or process change that affects the parameter.
- Absolute linearity is utilitzed to determine actual wiper voltage versus expected voltage as determined by wiper position when used as a potentiometer.
- (3) Relative linearity is utilized to determine the actual change in voltage between two successive tap positions when used as a potentiometer. It is a measure of the error in step size.
- (4) LSB = R_{TOT} / 63 or ($R_H R_L$) / 63, single pot (5) n = 0, 1, 2, ..., 63

⁽¹⁾ The minimum DC input voltage is -0.5V. During transitions, inputs may undershoot to -2.0V for periods of less than 20 ns. Maximum DC voltage on output pins is V_{CC} +0.5V, which may overshoot to V_{CC} +2.0V for periods of less than 20 ns.

Latch-up protection is provided for stresses up to 100 mA on address and data pins from -1V to V_{CC} +1V.

D.C. OPERATING CHARACTERISTICS

Over recommended operating conditions unless otherwise stated.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Icc	Power Supply Current	f _{SCK} = 2MHz, SO Open Inputs = GND			1	mA
I _{SB}	Standby Current (V _{CC} = 5.0V)	V _{IN} = GND or V _{CC} ; SO Open			1	μΑ
ILI	Input Leakage Current	V _{IN} = GND to V _{CC}			10	μΑ
I _{LO}	Output Leakage Current	$V_{OUT} = GND$ to V_{CC}			10	μΑ
V _{IL}	Input Low Voltage		-1		V _{CC} x 0.3	V
ViH	Input High Voltage		Vcc x 0.7		V _{CC} + 1.0	V
V _{OL1}	Output Low Voltage (V _{CC} = 3.0V)	I _{OL} = 3 mA			0.4	V

PIN CAPACITANCE (1)

Applicable over recommended operating range from $T_A=25^{\circ}C$, f=1.0 MHz, $VCC=\pm5.0$ V (unless otherwise noted).

Symbol	Test Conditions	Min	Тур	Max	Units	Conditions
Соит	Output Capacitance (SO)			8	pF	V _{OUT} =0V
Cin	Input Capacitance (CS, SCK, SI, WP, HOLD)			6	pF	V _{IN} =0V

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A.C. CHARACTERISTICS

Over recommended operating conditions unless otherwise stated.

SYMBOL	PARAMETER	Min	Тур	Max	UNITS	Test Conditions
tsu	Data Setup Time	50			ns	
t _H	Data Hold Time	50			ns	
t _{WH}	SCK High Time	125			ns	
t _{WL}	SCK Low Time	125			ns	
fsck	Clock Frequency	DC		3	MHz	
t _{LZ}	HOLD to Output Low Z			50	ns	
t _{RI} ⁽¹⁾	Input Rise Time			2	μs	
t _{FI} ⁽¹⁾	Input Fall Time			2	μs	0 50 5
t _{HD}	HOLD Setup Time	100			ns	$C_L = 50pF$
t _{CD}	HOLD Hold Time	100			ns	
twc	Write Cycle Time			10	ms	
t _V	Output Valid from Clock Low			250	ns	
t _{HO}	Output Hold Time	0			ns	
t _{DIS}	Output Disable Time			250	ns	
t _{HZ}	HOLD to Output High Z			100	ns	
tcs	CS High Time	250			ns	
tcss	CS Setup Time	250			ns	
tcsh	CS Hold Time	250			ns	

NOTE:

POWER UP TIMING (1)

Over recommended operating conditions unless otherwise stated.

Symbol	Parameter	Min	Тур	Max	Units
t _{PUR}	Power-up to Read Operation			1	ms
t _{PUW}	Power-up to Write Operation			1	ms

Note:

(1) This parameter is tested initially and after a design or process change that affects the parameter.

⁽¹⁾ This parameter is tested initially and after a design or process change that affects the parameter.

WRITE CYCLE LIMITS

Over recommended operating conditions unless otherwise stated.

Symbol	Parameter	Min	Тур	Max	Units
twR	Write Cycle Time			5	ms

RELIABILITY CHARACTERISTICS

Over recommended operating conditions unless otherwise stated.

Symbol	Parameter	Reference Test Method	Min	Тур	Max	Units
N _{END} ⁽¹⁾	Endurance	MIL-STD-883, Test Method 1033	1,000,000			Cycles/Byte
T _{DR} ⁽¹⁾	Data Retention	MIL-STD-883, Test Method 1008	100			Years
V _{ZAP} ⁽¹⁾	ESD Susceptibility	MIL-STD-883, Test Method 3015	2000			Volts
I _{LTH} ⁽¹⁾	Latch-Up	JEDEC Standard 17	100			mA

Figure 1. Sychronous Data Timing

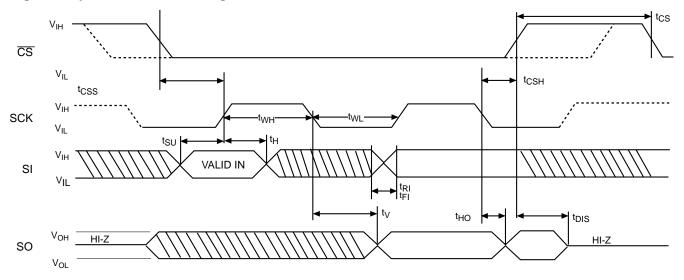
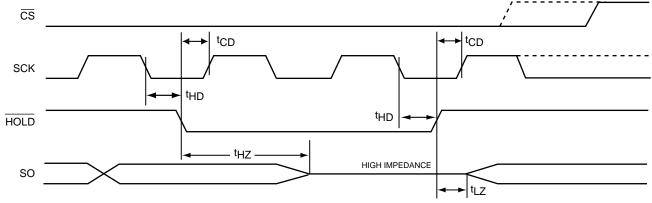


Figure 2. HOLD Timing



Note:

- (1) This parameter is tested initially and after a design or process change that affects the parameter.
- (2) t_{PUR} and t_{PUW} are the delays required from the time V_{CC} is stable until the specified operation can be initiated.
- (3) Dashed Line= mode (1, 1) — —

INSTRUCTION AND REGISTER DESCRIPTION

DEVICE TYPE / ADDRESS BYTE

The first byte sent to the CAT5401 from the master/ processor is called the Device Address Byte. The most significant four bits of the Device Type address are a device type identifier. These bits for the CAT5401 are fixed at 0101[B] (refer to Table 1).

The two least significant bits in the slave address byte, A1 - A0, are the internal slave address and must match the physical device address which is defined by the state of the A1 - A0 input pins for the CAT5401 to successfully continue the command sequence. Only the device which slave address matches the incoming device address sent by the master executes the instruction. The A1 - A0 inputs can be actively driven by CMOS input signals or tied to $V_{\rm CC}$ or $V_{\rm SS}$. The remaining two bits in the device address byte must be set to 0.

INSTRUCTION BYTE

The next byte sent to the CAT5401 contains the instruction and register pointer information. The four most significant bits used provide the instruction opcode I [3:0]. The R1 and R0 bits point to one of the four data registers of each associated potentiometer. The least two significant bits point to one of four Wiper Control Registers. The format is shown in Table 2.

Data Register Selection

Data Register Selected	R1	R0
DR0	0	0
DR1	0	1
DR2	1	0
DR3	1	1

Table 1. Identification Byte Format

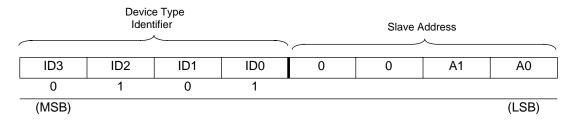
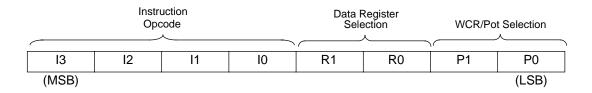


Table 2. Instruction Byte Format



WIPER CONTROL AND DATA REGISTERS

Wiper Control Register (WCR)

The CAT5401 contains four 6-bit Wiper Control Registers, one for each potentiometer. The Wiper Control Register output is decoded to select one of 64 switches along its resistor array. The contents of the WCR can be altered in four ways: it may be written by the host via Write Wiper Control Register instruction; it may be written by transferring the contents of one of four associated Data Registers via the XFR Data Register instruction, it can be modified one step at a time by the Increment/decrement instruction (see Instruction section for more details). Finally, it is loaded with the content of its data register zero (DR0) upon power-up.

The Wiper Control Register is a volatile register that loses its contents when the CAT5401 is powered-down. Although the register is automatically loaded with the value in DR0 upon power-up, this may be different from the value present at power-down.

Data Registers (DR)

Each potentiometer has four 6-bit non-volatile Data Registers. These can be read or written directly by the host. Data can also be transferred between any of the four Data Registers and the associated Wiper Control Register. Any data changes in one of the Data Registers is a non-volatile operation and will take a maximum of 5ms.

Write in Process

The contents of the Data Registers are saved to nonvolatile memory when the CS input goes HIGH after a write sequence is received. The status of the internal write cycle can be monitored by issuing a Read Status command to read the Write in Process (WIP) bit.

INSTRUCTIONS

Five of the ten instructions are three bytes in length. These instructions are:

- Read Wiper Control Register read the current wiper position of the selected potentiometer in the WCR
- Write Wiper Control Register change current wiper position in the WCR of the selected potentiometer
- Read Data Register read the contents of the selected Data Register
- Write Data Register write a new value to the selected Data Register
- Read Status Read the status of the WIP bit which

Table 3. Instruction Set

	Instruction Set					Set			
Instruction	13	12	11	10	R1	R0	WCR1/ P1	WCR0/ P0	Operation
Read Wiper Control Register	1	0	0	1	0	0	1/0	1/0	Read the contents of the Wiper Control Register pointed to by P1-P0
Write Wiper Control Register	1	0	1	0	0	0	1/0	1/0	Write new value to the Wiper Control Register pointed to by P1-P0
Read Data Register	1	0	1	1	1/0	1/0	1/0	1/0	Read the contents of the Data Register pointed to by P1-P0 and R1-R0
Write Data Register	1	1	0	0	1/0	1/0	1/0	1/0	Write new value to the Data Register pointed to by P1-P0 and R1-R0
XFR Data Register to Wiper Control Register	1	1	0	1	1/0	1/0	1/0	1/0	Transfer the contents of the Data Register pointed to by P1-P0 and R1-R0 to its associated Wiper Control Register
XFR Wiper Control Register to Data Register	1	1	1	0	1/0	1/0	1/0	1/0	Transfer the contents of the Wiper Control Register pointed to by P1-P0 to the Data Register pointed to by R1-R0
Global XFR Data Registers to Wiper Control Registers	0	0	0	1	1/0	1/0	0	0	Transfer the contents of the Data Registers pointed to by R1-R0 of all four pots to their respective Wiper Control Register
Global XFR Wiper Control Registers to Data Register	1	0	0	0	1/0	1/0	0	0	Transfer the contents of both Wiper Control Registers to their respective data Registers pointed to by R1-R0 of all four pots
Increment/Decrement Wiper Control Register	0	0	1	0	0	0	1/0	1/0	Enable Increment/decrement of the Control Latch pointed to by P1-P0
Read Status (WIP bit)	0	1	0	1	0	0	0	1	Read WIP bit to check internal write cycle status

Note: 1/0 = data is one or zero

when set to "1" signifies a write cycle is in progress.

The basic sequence of the three byte instructions is illustrated in Figure 8. These three-byte instructions exchange data between the WCR and one of the Data Registers. The WCR controls the position of the wiper. The response of the wiper to this action will be delayed by twRL. A transfer from the WCR (current wiper position), to a Data Register is a write to non-volatile memory and takes a minimum of twR to complete. The transfer can occur between one of the four potentiometers and one of its associated registers; or the transfer can occur between all potentiometers and one associated register.

Four instructions require a two-byte sequence to complete, as illustrated in Figure 7. These instructions transfer data between the host/processor and the CAT5401; either between the host and one of the data registers or directly between the host and the Wiper Control Register. These instructions are:

- XFR Data Register to Wiper Control Register This transfers the contents of one specified Data Register to the associated Wiper Control Register.
- —XFR Wiper Control Register to Data Register This transfers the contents of the specified Wiper Control Register to the specified associated Data Register.
- Global XFR Data Register to Wiper

Control Register

This transfers the contents of all specified Data Registers to the associated Wiper Control Registers.

Global XFR Wiper Counter Register to Data Register

This transfers the contents of all Wiper Control Registers to the specified associated Data Registers.

INCREMENT/DECREMENT COMMAND

The final command is Increment/Decrement (Figure 5 and 9). The Increment/Decrement command is different from the other commands. Once the command is issued the master can clock the selected wiper up and/or down in one segment steps; thereby providing a fine tuning capability to the host. For each SCK clock pulse (thigh) while SI is HIGH, the selected wiper will move one resistor segment towards the RH terminal. Similarly, for each SCK clock pulse while SI is LOW, the selected wiper will move one resistor segment towards the RL terminal.

See Instructions format for more detail.



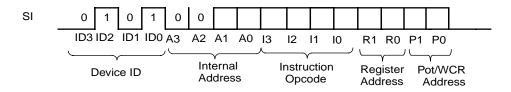


Figure 8. Three-Byte Instruction Sequence

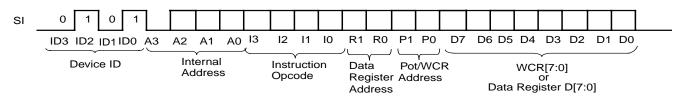


Figure 9. Increment/Decrement Instruction Sequence

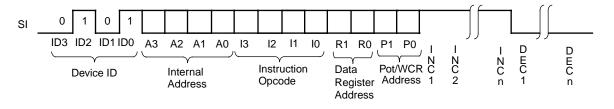
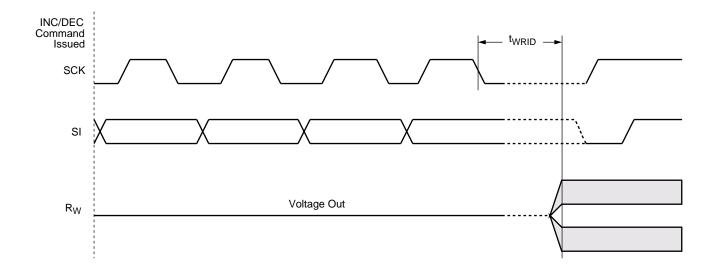


Figure 10. Increment/Decrement Timing Limits



INSTRUCTION FORMAT

Read Wiper Control Register (WCR)

	DI	ΕVI	CE	Α	DD	RE	SSE	ES		IN	ST	RL	JC	ΓΙΟ	N				DA	TA					
CS	0	1	0	1	0	0	A 1	A0	1	0	0	1	0	0	P1	P0	7 0	6 0	5	4	3	2	1	0	CS

Write Wiper Control Register (WCR)

	DI	ΕVI	CE	Α	DD	RE	SSE	ES		IN	ST	RL	JC	ΓΙΟ	N				D	ATA	\				
CS	0	1	0	1	0	0	A 1	Α0	1	0	1	0	0	0	P1	P0	7 0	6 0	5	4	3	2	1	0	CS

Read Data Register (DR)

I		DI	ΕVI	CE	Α	DD	RE	SS	ES		IN	ST	RU	ICTI	ON					DA	TΑ					
	CS	0	1	0	1	0	0	A 1	A0	1	0	1	1	R1	R0	P1	P0	7	6	5	4	3	2	1	0	<u>CS</u>

Write Data Register (DR)

	DI	ΕVI	CE	ΕΑ	DD	RE	SS	ES		IN	IST	Rl	JCTI	ON					DA	TA	ı					
cs	0	1	0	1	0	0	A 1	Α0	1	1	0	0	R1	R0	P1	P0	7	6	5	4	3	2	1	0	CS	High Voltage Write Cycle

Read (WIP) Status

	DI	EVI	CE	Α	DD	RE	SSI	ES		IN	ST	Rι	JC	ГІС	N					DA	TA				
CS	0	1	0	1	0	0	A 1	A0	0	1	0	1	0	0	0	1	7	6	5	4	3	2	1	W	CS
																	0	0	0	0	0	0	0	ı P	

INSTRUCTION FORMAT (continued)

Global Transfer Data Register (DR) to Wiper Control Register (WCR)

	DI	ΕVΙ	CE	Al	DDF	RES	SSE	S		INS	STF	RUG	CTIC	N			
CS	0	1	0	1	0	0	A 1	Α0	0	0	0	1	R1	R0	0	0	cs

Global Transfer Wiper Control Register (WCR) to Data Register (DR)

	D	ΕV	ICE	A	DDI	RES	SSE	S		INS	STR	RUC	CTIC	N				
cs	0	1	0	1	0	0	A1	A0	1	0	0	0	R1	R0	0	0	cs	High Voltage Write Cycle

Transfer Wiper Control Register (WCR) to Data Register (DR)

	D	ΕV	ICE	ΕA	DDI	RES	SSE	S		INS	STF	RUC	CTI	ON				
CS	0	1	0	1	0	0	A 1	A0	1	1	1	0	R1	R0	P1	P0	CS	High Voltage Write Cycle

Transfer Data Register (DR) to Wiper Control Register (WCR)

	DI	EVI	CE	Α	DDI	RES	SSE	S		IN:	STE	RU	СТІ	ON			
CS	0	1	0	1	0	0	A1	A0	1	1	0	1	R1	R0	P1	P0	CS

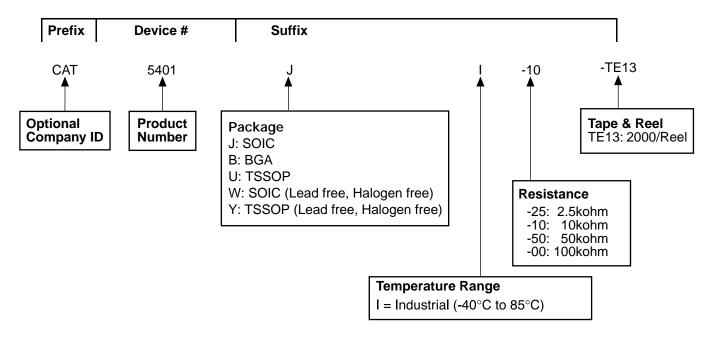
Increment (I)/Decrement (D) Wiper Control Register (WCR)

	DI	ΕVΙ	CE	Α	DDI	RES	SSE	S	ı	NS	TR	UC	CTIC	NC					DATA			
CS	0	1	0	1	0	0	A1	A0	0	0	1	0	0	0	P1	P0	I/D	I/D	• • •	I/D	I/D	CS

Notes:

(1) Any write or transfer to the Non-volatile Data Registers is followed by a high voltage cycle after $\overline{\text{CS}}$ goes high.

ORDERING INFORMATION

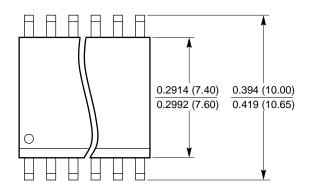


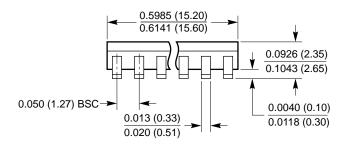
Notes:

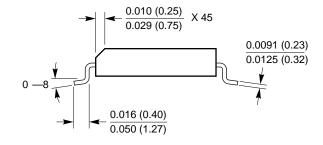
(1) The device used in the above example is a CAT5401JI-10-TE13 (SOIC, Industrial Temperature, 10kohm, Tape & Reel)

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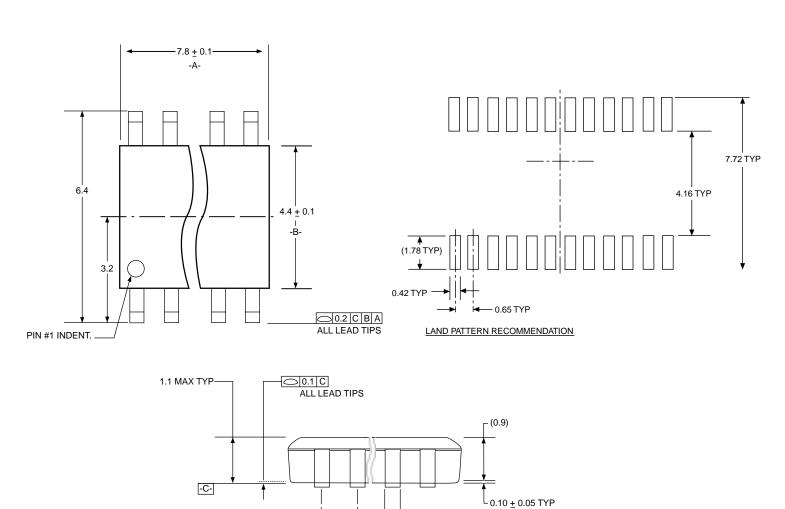
PACKAGING INFORMATION 24-LEAD 300 MIL WIDE SOIC (J)

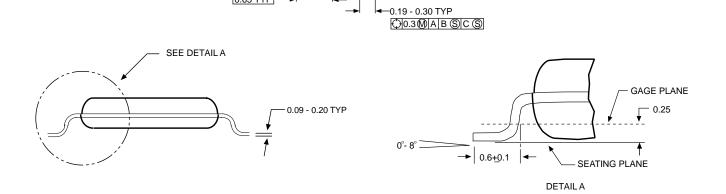






PACKAGING INFORMATION CON'T 24 Lead TSSOP (U)

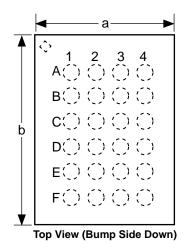


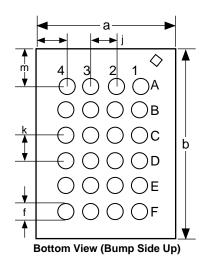


0.65 TYP

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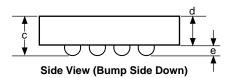
PACKAGING INFORMATION CON'T 24 Ball BGA





Note: Drawing not to scale

♦ = Die orientation mark



			Millimete	rs		Inches	
	Symbol	Min	Nom	Max	Nom	Min	Max
Package Body Dimension X	а	TBD	TBD	TBD	TBD	TBD	TBD
Package Body Dimension Y	b	TBD	TBD	TBD	TBD	TBD	TBD
Package Height	С	0.635	0.505	0.765	0.02500	0.01988	0.03012
Package Body Thickness	d	0.433	0.395	0.471	0.01705	0.01555	0.01854
Ball Height	е	0.202	0.110	0.294	0.00795	0.00433	0.01157
Ball Diameter	f	0.284	0.180	0.388	0.01118	0.00709	0.01528
Total Ball Count	g	24					
Ball Count X Axis	h	4					
Ball Count Y Axis	i	6					
Pins Pitch X Axis	j	0.5					
Pins Pitch Y Axis	k	0.5					
Edge to Ball Center (Corner)							
Distance Along X	l l	TBD	TBD	TBD	TBD	TBD	TBD
Edge to Ball Center (Corner)							
Distance Along Y	m	TBD	TBD	TBD	TBD	TBD	TBD

REVISION HISTORY

Date	Rev.	Reason
3/31/2004	F	Changed Preliminary designation to Final
		Eliminated Commercial temp range in all areas
		Updated Potentiometer characteristics notes
		Updated Pin Descriptions (A0, A1 and WP)
		Updated notes for Absolute Max Ratings and Potentiometer Characteristics

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